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BTW69-1200N

50 A – 1200 V non insulated SCR thyristor

Datasheet - production data



Description

Available in non insulated TOP3 high power package, the BTW69-1200N is suitable for applications where power switching and power dissipation are critical, such as by-pass switch, controlled AC rectifier bridge, in solid state relay, battery charger, uninterruptible power supply, welding equipment and motor driver applications.

Based on a clip assembly technology, the BTW69-1200N offers a superior performance in surge current handling and thermal cooling capabilities.

Table 1. Device summary

Symbol	Value
I _{T(RMS)}	50 A
V _{DRM} /V _{RRM}	1200 V
I _{GT}	50 mA

Features

- On-state rms current: 50 A
- Blocking voltage: 1200 V
- Gate current: 50 mA

Applications

- Solid state relay
- Battery charging system
- Uninterruptible power supply
- Variable speed motor drive
- Industrial welding systems
- By pass AC switch

1 Characteristics

Symbol	Parameter	Value	Unit		
I _{T(RMS)}	On-state current rms (180° conduction ang	gle)	T _c = 102 °C	50	А
$IT_{(AV)}$	Average on-state current (180° conduction	angle)	T _c = 102 °C	31	А
1	Non repetitive surge peak on-state	t _p = 8.3 ms	T 25 °C	763	٨
' TSM	ITSM current t		$T_j = 25 C$	700	А
ľt	I ^² t Value	2450	A ² s		
dl/dt	Critical rate of rise of on-state current Gate supply: $I_G = 100$ mA, $dI_G/dt = 1$ A/µs			100	A∕µs
I _{GM}	Peak gate current $t_p = 20 \ \mu s$ $T_j = 125 \ ^{\circ}C$		8	А	
$P_{G(AV)}$	Average gate power dissipation	•	T _j = 125 °C	1	W
T _{stg}	Storage junction temperature range			- 40 to + 150	°C
Тj	Operating junction temperature range			- 40 to + 125	5
V_{GM}	Maximum peak reverse gate voltage			5	V

Table 2. Absolute maximum	ratings	(limiting	values)
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Table 3. Electrical characteristics ($T_i = 25 \text{ °C}$, unless otherwise specified)

Symbol	Test conditions	Value	Unit		
			MIN.	8	
I GT	V_D = 12 V, R_L = 33 Ω		MAX.	50	ША
V _{GT}			MAX.	1.3	V
V_{GD}	$V_D = V_{DRM,} R_L = 3.3 \text{ k}\Omega$	T _j = 125 °C	MIN.	0.2	V
Ι _Η	I _T = 500 mA, gate open		MAX.	100	mA
١L	$I_{G} = 1.2 \text{ x } I_{GT}$		TYP.	125	mA
t _{gt}	$\textbf{I}_T = 50 \text{ A}, \text{ V}_D = \textbf{V}_{DRM}, \text{ I}_G = 200 \text{ mA}, \text{ dI}_G/\text{dt} = 0.2 \text{ A}/\mu\text{s}$		TYP.	2	μs
dV/dt	$V_{D} = 67\% V_{DRM}$, gate open	T _j = 125 °C	MIN.	1000	V/µs
tq	$\begin{split} V_D &= 800 \text{ V}, \text{ I}_{TM} = 50 \text{ A}, \text{ V}_R = 75 \text{ V}, \\ t_p &= 100 \mu\text{s}, $	T _j = 125 °C	TYP.	100	μs
V _{TM}	I _{TM} = 100 A, t _p = 380 μs	T _j = 25 °C	MAX.	1.6	V
V _{t0}	Threshold voltage	T _j = 125 °C	MAX.	0.9	V
R _D	Dynamic resistance	T _j = 125 °C	MAX.	8.5	mΩ
I _{DRM}	V _D = V _{DRM}	T _j = 25 °C	ΜΔΥ	10	μA
I _{RRM}	$V_{R} = V_{RRM}$	T _j = 125 °C		5	mA



	Table 4. Thermal resistance					
Symbol	Parameter Value Unit					
R _{th(j-c)}	Junction to case (DC, typ.)	0.45	°C/W			
R _{th(j-a)}	Junction to ambient (DC)	50	°C/W			

Figure 1. Maximum average power dissipation versus average on-state current



Figure 3. Average and DC on-state current versus case temperature

Figure 2. Correlation between maximum average power dissipation and maximum allowable temperatures



Figure 4. Average and DC on-state current versus ambient temperature





Figure 5. Relative variation of thermal impedance versus pulse duration



Figure 7. Relative variation of holding, and latching currents versus junction temperature (typical values)



Figure 9. Non repetitive surge peak on-state current and corresponding value of I²t versus sinusoidal pulse



Figure 6. Relative variation of gate trigger

current and gate trigger voltage versus junction temperature (typical value)

Figure 8. Surge peak on-state current versus number of cycles



Figure 10. On-state characteristics (maximum values)





DocID024685 Rev 1



of blocking voltage (600 and 800 V)







2 Package information

- Epoxy meets UL94,V0
- Lead-free packages
- Cooling method: by conduction (C)
- Recommended torque value: 0.9 to 1.2 N·m

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Figure 13. TOP3 dimension definitions



	Dimensions				
Ref.	Millimeters		Inc	hes	
	Min.	Max.	Min.	Max.	
А	4.4	4.6	0.173	0.181	
В	1.45	1.55	0.057	0.061	
С	14.35	15.60	0.565	0.614	
D	0.5	0.7	0.020	0.028	
E	2.7	2.9	0.106	0.114	
F	15.8	16.5	0.622	0.650	
G	20.4	21.1	0.815	0.831	
Н	15.1	15.5	0.594	0.610	
J	5.4	5.65	0.213	0.222	
К	3.4	3.65	0.134	0.144	
ØL	4.08	4.17	0.161	0.164	
Р	1.20	1.40	0.047	0.055	
R	4.60 typ.		0.18	1 typ.	

Table 5. TOP3 dimension values



3 Ordering information





Table 6. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
BTW69-1200N	BTW691200N	TOP3	4.55 g	30	Tube

4 Revision history

	Table	7.	Document	revision	history
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Date	Revision	Changes
14-Jun-2013	1	Initial release.



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DocID024685 Rev 1